# **150 mA CMOS Low Iq Low-Dropout Voltage Regulator**

The NCP561 series of fixed output low dropout linear regulators are designed for handheld communication equipment and portable battery powered applications which require low quiescent. The NCP561 series features an ultra–low quiescent current of  $3.0 \ \mu$ A. Each device contains a voltage reference unit, an error amplifier, a PMOS power transistor, resistors for setting output voltage, current limit, and temperature limit protection circuits.

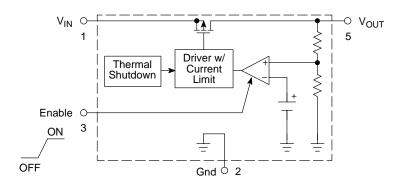
The NCP561 has been designed to be used with low cost ceramic capacitors and requires a minimum output capacitor of 1.0  $\mu$ F. The device is housed in the micro–miniature TSOP–5 surface mount package. Standard voltage versions are 1.5, 1.8, 2.5, 2.7, 2.8, 3.0, 3.3 and 5.0 V.

#### Features

- Low Quiescent Current of 3.0 µA Typical
- Low Dropout Voltage of 170 mV at 150 mA
- Low Output Voltage Option
- Output Voltage Accuracy of 2.0%
- Industrial Temperature Range of -40°C to 85°C

#### **Typical Applications**

- Battery Powered Instruments
- Hand–Held Instruments
- Camcorders and Cameras



This device contains 28 active transistors





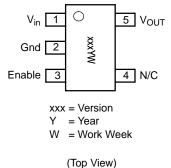
# **ON Semiconductor®**

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TSOP-5 (SOT23-5, SC59-5) SN SUFFIX CASE 483





#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

#### **PIN FUNCTION DESCRIPTION**

Pin No.	Pin Name	Description
1	Vin	Positive power supply input voltage.
2	Gnd	Power supply ground.
3	Enable	This input is used to place the device into low-power standby. When this input is pulled low, the device is disabled. If this function is not used, Enable should be connected to Vin.
4	N/C	No internal connection.
5	V <sub>OUT</sub>	Regulated output voltage.

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V <sub>IN</sub>	6.0	V
Enable Voltage	Enable	–0.3 to V <sub>IN</sub> +0.3	V
Output Voltage	V <sub>OUT</sub>	–0.3 to V <sub>IN</sub> +0.3	V
Power Dissipation and Thermal Characteristics Power Dissipation Thermal Resistance, Junction to Ambient	Ρ <sub>D</sub> R <sub>θJA</sub>	Internally Limited 250	W ∘C/W
Operating Junction Temperature	TJ	+125	°C
Operating Ambient Temperature	T <sub>A</sub>	-40 to +85	°C
Storage Temperature	T <sub>stg</sub>	–55 to +150	°C

This device series contains ESD protection and exceeds the following tests: Human Body Model 2000 V per MIL–STD–883, Method 3015 Machine Model Method 200 V
Latch up capability (85°C) ±100 mA DC with trigger voltage.

ELECTRICAL CHARACTERISTICS	$(V_{IN} = V_{OUT(nom.)})$	+ 1.0 V, V	$V_{\text{enable}} = V_{\text{IN}},$	$C_{IN}$ = 1.0 $\mu$ F,	$C_{OUT}$ = 1.0 $\mu$ F, T <sub>J</sub>	= 25°C, unless
otherwise noted.)	· · · ·					

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage (T <sub>A</sub> = 25°C, I <sub>OUT</sub> = 1.0 mA) 1.5 V 1.8 V 2.5 V 2.7 V 2.8 V 3.0 V 3.3 V 5.0 V	V <sub>OUT</sub>	1.455 1.746 2.425 2.646 2.744 2.940 2.234 4.90	1.5 1.8 2.5 2.7 2.8 3.0 3.3 5.0	1.545 1.854 2.575 2.754 2.856 3.060 3.366 5.10	V
Line Regulation 1.5 V–4.4 V ( $V_{in} = V_{o(nom.)} + 1.0$ V to 6.0 V) 4.5 V–5.0 V ( $V_{in} = 5.5$ V to 6.0 V)	Reg <sub>line</sub>		10 10	20 20	mV
Load Regulation (I <sub>OUT</sub> = 10 mA to 150 mA)	Reg <sub>load</sub>	-	30	60	mV
Output Current (V <sub>out</sub> = (V <sub>out</sub> at I <sub>out</sub> = 150 mA) $-3.0\%$ ) 1.5 V to 3.9 V (V <sub>IN</sub> = V <sub>o(nom.)</sub> + 2.0 V) 4.0 V to 5.0 V (V <sub>IN</sub> = 6.0 V)	I <sub>o(nom.)</sub>	150 150			mA
Dropout Voltage ( $T_A = -40^{\circ}$ C to 85°C, $I_{OUT} = 150$ mA, Measured at V <sub>OUT</sub> -3.0%) 1.5 V - 1.7 V 1.8 V - 2.4 V 2.5 V - 2.7 V 2.8 V - 3.2 V 3.3 V - 4.9 V 5.0 V	V <sub>IN</sub> –V <sub>OUT</sub>	- - - -	330 240 150 140 130 120	500 360 250 230 200 190	mV
Quiescent Current (Enable Input = 0 V) (Enable Input = $V_{IN}$ , $I_{OUT}$ = 1.0 mA to $I_{o(nom.)}$ )	lq	-	0.1 4.0	1.0 8.0	μΑ
Output Short Circuit Current 1.5 V to 3.9 V ( $V_{IN} = V_{o(nom.)} + 2.0$ V) 4.0 V to 5.0 V ( $V_{IN} = 6.0$ V)	I <sub>OUT(max)</sub>	160 160	400 400	800 800	mA
Output Voltage Noise (f = 20 Hz to 100 kHz, $V_{OUT}$ = 3.0, V I <sub>OUT</sub> = 1.0 V)	V <sub>n</sub>	-	60	-	μVrms
Enable Input Threshold Voltage (Voltage Increasing, Output Turns On, Logic High) (Voltage Decreasing, Output Turns Off, Logic Low)	$V_{th(en)}$	1.3 -		_ 0.2	V
Output Voltage Temperature Coefficient	т <sub>с</sub>	_	±100	-	ppm/°C

3. Maximum package power dissipation limits must be observed.

$$PD = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

4. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.

# **TYPICAL CHARACTERISTICS**

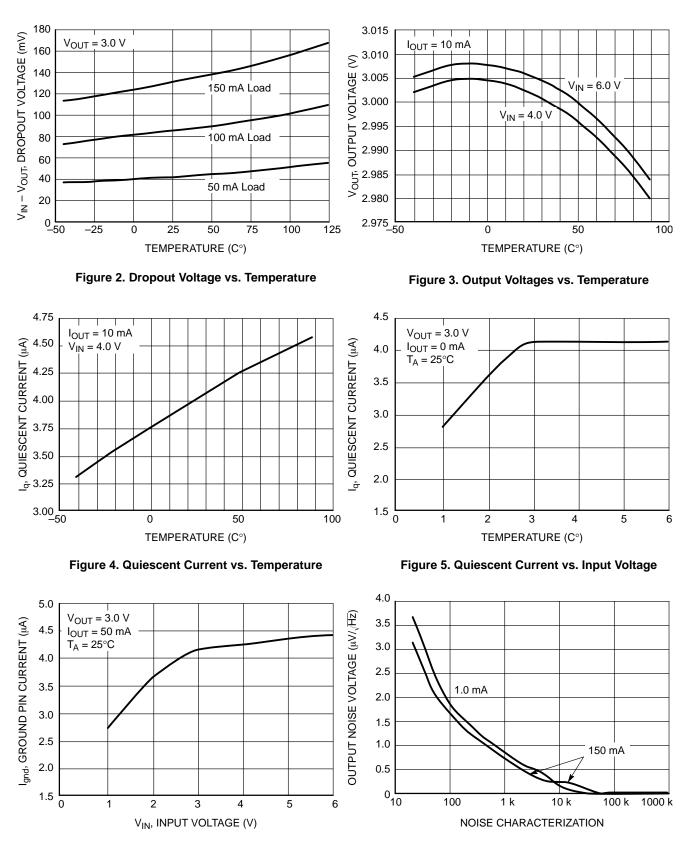
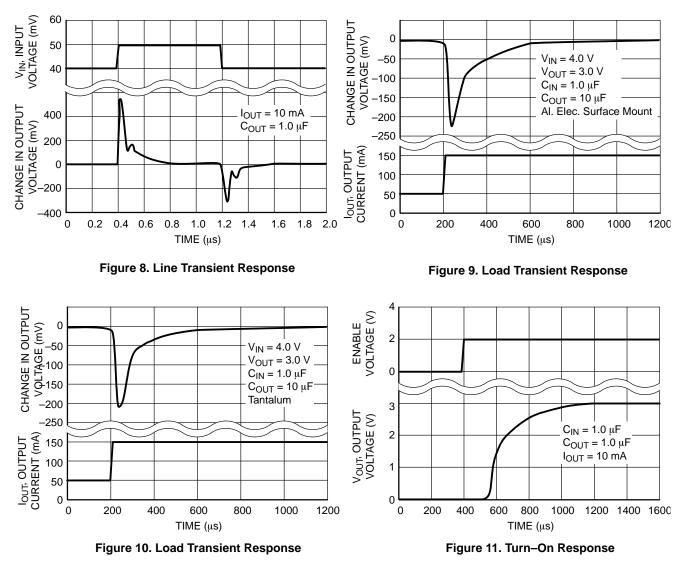




Figure 7. Output Noise Voltage

### **TYPICAL CHARACTERISTICS**



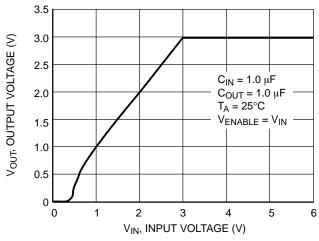


Figure 12. Output Voltage vs. Input Voltage

# DEFINITIONS

#### Load Regulation

The change in output voltage for a change in output current at a constant temperature.

#### **Dropout Voltage**

The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 3.0% below its nominal. The junction temperature, load current, and minimum input supply requirements affect the dropout level.

#### **Maximum Power Dissipation**

The maximum total dissipation for which the regulator will operate within its specifications.

#### **Quiescent Current**

The quiescent current is the current which flows through the ground when the LDO operates without a load on its output: internal IC operation, bias, etc. When the LDO becomes loaded, this term is called the Ground current. It is actually the difference between the input current (measured through the LDO input pin) and the output current.

#### Line Regulation

The change in output voltage for a change in input voltage. The measurement is made under conditions of low dissipation or by using pulse technique such that the average chip temperature is not significantly affected.

#### Line Transient Response

Typical over and undershoot response when input voltage is excited with a given slope.

#### **Thermal Protection**

Internal thermal shutdown circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated at typically 160°C, the regulator turns off. This feature is provided to prevent failures from accidental overheating.

## Maximum Package Power Dissipation

The maximum power package dissipation is the power dissipation level at which the junction temperature reaches its maximum operating value, i.e. 125°C. Depending on the ambient power dissipation and thus the maximum available output current.

#### **APPLICATIONS INFORMATION**

A typical application circuit for the NCP561 series is shown in Figure 13.

#### Input Decoupling (C1)

A 1.0  $\mu$ F capacitor either ceramic or tantalum is recommended and should be connected close to the NCP561 package. Higher values and lower ESR will improve the overall line transient response.

TDK capacitor: C2012X5R1C105K, or C1608X5R1A105K

#### **Output Decoupling (C2)**

The NCP561 is a stable Regulator and does not require any specific Equivalent Series Resistance (ESR) or a minimum output current. Capacitors exhibiting ESRs ranging from a few m $\Omega$  up to 3.0  $\Omega$  can thus safely be used. The minimum decoupling value is 1.0  $\mu$ F and can be augmented to fulfill stringent load transient requirements. The regulator accepts ceramic chip capacitors as well as tantalum devices. Larger values improve noise rejection and load regulation transient response.

TDK capacitor: C2012X5R1C105K, or C1608X5R1A105K, or C3216X7R1C105K

#### **Enable Operation**

The enable pin will turn on the regulator when pulled high and turn off the regulator when pulled low. These limits of threshold are covered in the electrical specification section of this data sheet. If the enable is not used then the pin should be connected to  $V_{IN}$ .

#### Hints

Please be sure the Vin and Gnd lines are sufficiently wide. When the impedance of these lines is high, there is a chance to pick up noise or cause the regulator to malfunction.

Set external components, especially the output capacitor, as close as possible to the circuit, and make leads a short as possible.

#### Thermal

As power across the NCP561 increases, it might become necessary to provide some thermal relief. The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material and also the ambient temperature effect the rate of temperature rise for the part. This is stating that when the NCP561 has good thermal conductivity through the PCB, the junction temperature will be relatively low with high power dissipation applications.

The maximum dissipation the package can handle is given by:

$$PD = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

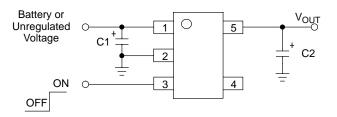
If junction temperature is not allowed above the maximum  $125^{\circ}$ C, then the NCP561 can dissipate up to  $400 \text{ mW} @ 25^{\circ}$ C.

The power dissipated by the NCP561 can be calculated from the following equation:

$$P_{tot} = [V_{in} * I_{gnd} (I_{out})] + [V_{in} - V_{out}] * I_{out}$$
  
or

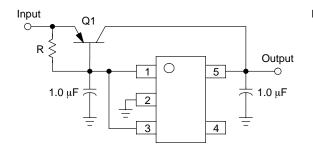
$$V_{\text{INMAX}} = \frac{P_{\text{TOT}} + V_{\text{OUT}} * I_{\text{OUT}}}{I_{\text{GND}} + I_{\text{OUT}}}$$

If a 150 mA output current is needed then the ground current from the data sheet is  $4.0 \ \mu$ A. For an NCP561SN30T1 (3.0 V), the maximum input voltage will then be 5.6 V.



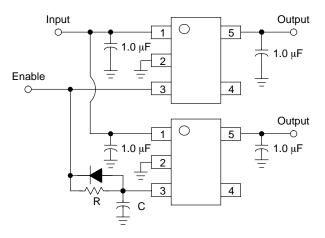
**Figure 13. Typical Application Circuit** 

## **APPLICATION CIRCUITS**



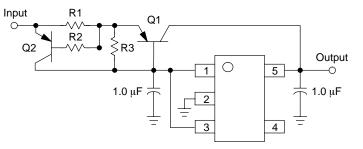
## Figure 14. Current Boost Regulator

The NCP561 series can be current boosted with a PNP transistor. Resistor R in conjunction with V<sub>BE</sub> of the PNP determines when the pass transistor begins conducting; this circuit is not short circuit proof. Input/Output differential voltage minimum is increased by V<sub>BE</sub> of the pass resistor.



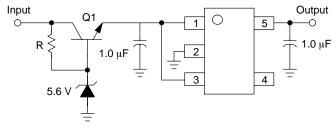
#### Figure 16. Delayed Turn-on

If a delayed turn–on is needed during power up of several voltages then the above schematic can be used. Resistor R, and capacitor C, will delay the turn–on of the bottom regulator.



#### Figure 15. Current Boost Regulator with Short Circuit Limit

Short circuit current limit is essentially set by the V<sub>BE</sub> of Q2 and R1.  $I_{SC}$  = ((V<sub>BEQ2</sub> - ib \* R2) / R1) +  $I_{O(max) Regulator}$ 



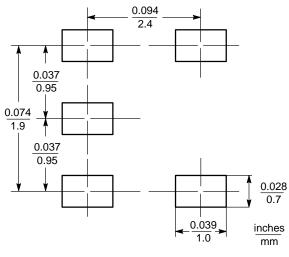
#### Figure 17. Input Voltages Greater than 6.0 V

A regulated output can be achieved with input voltages that exceed the 6.0 V maximum rating of the NCP561 series with the addition of a simple pre–regulator circuit. Care must be taken to prevent Q1 from overheating when the regulated output ( $V_{OUT}$ ) is shorted to G<sub>nd</sub>.

## MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



TSOP-5

(Footprint Compatible with SOT23-5)

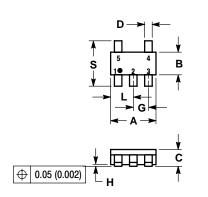
# ORDERING INFORMATION

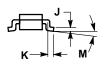
Device	Nominal Output Voltage	Marking	Package	Shipping
NCP561SN15T1	1.5	LDA		
NCP561SN18T1	1.8	LEV		
NCP561SN25T1	2.5	LDC		
NCP561SN27T1	2.7	LEX	TOOD F	3000 Units/
NCP561SN28T1	2.8	LDD	TSOP-5	7″ Tape & Reel
NCP561SN30T1	3.0	LDE		
NCP561SN33T1	3.3	LDF		
NCP561SN50T1	5.0	LDH		

Additional voltages are available upon request by contacting your ON Semiconductor representative.

## PACKAGE DIMENSIONS

TSOP-5 (SOT23-5, SC59-5) SN SUFFIX PLASTIC PACKAGE CASE 483-01 **ISSUE B** 





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.1142	0.1220
В	1.30	1.70	0.0512	0.0669
С	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.05	0.0335	0.0413
Н	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
Κ	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
М	0 °	10 °	0 °	10°
S	2.50	3.00	0.0985	0.1181

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